

MOS INTEGRATED CIRCUIT μ PD17P719

4-BIT SINGLE-CHIP MICROCONTROLLER WITH BUILT-IN HARDWARE DEDICATED TO DIGITAL TUNING SYSTEMS

The μ PD17P719 is produced by replacing the built-in masked ROM of the μ PD17717, μ PD17718, and μ PD17719 with a one-time PROM.

The μ PD17P719 allows programs to be written once, so that the μ PD17P719 is suitable for preproduction in μ PD17717, μ PD17718, or μ PD17719 system development or low-volume production.

When reading this document, also refer to the publications on the μ PD17717, μ PD17718, or μ PD17719.

The electrical characteristics (including power supply currents) and PLL analog characteristics of the μ PD17P719 differ from those of the μ PD17717, μ PD17718, and μ PD17719. In high-volume application set production, carefully check those differences.

FEATURES

• Compatible with the μ PD17717, μ PD17718, and μ PD17719 • Built-in one-time PROM : 32K bytes (16384 × 16 bits)

• Supply voltage : PLL operation : VDD = 4.5 to 5.5 V

CPU operation: VDD = 3.5 to 5.5 V

ORDERING INFORMATION

Part number	Package
μPD17P719GC-3B9	80-pin plastic QFP (14 × 14 mm, 0.65-mm pitch)

The information in this document is subject to change without notice.



FUNCTION OVERVIEW

(1/2)

Item	Product	μPD17717	μPD17718	μPD17719	μPD17P719			
Prog	ram memory (ROM)	12288 × 16 bits (masked ROM)	16384 × 16 bits (masked ROM)		16384 × 16 bits (one-time PROM)			
	eral-purpose data ory (RAM)	1120 × 4 bits		1776 × 4 bits				
Instruction execution time 1.78 μ s (with fx = 4.5-MHz crystal)								
Gene	eral-purpose ports	I/O ports : 46Input ports : 12Output ports : 4						
Stack level								
Inter	rupt	,	ing edge and INT0 to II 0 to 3, serial interfaces	*				
Timers 5 channels • Basic timer (clock: 10, 20, 50, 100 Hz) • 8-bit timer with gate counter (clock: 1 k, 2 k, 10 k, 100 kHz) • 8-bit timer (clock: 1 k, 2 k, 10 k, 100 kHz) • 8-bit timer, also used for PWM (clock: 440 Hz, 4.4 kHz) : 1 channel					channel channels			
A/D o	converter	8 bits × 6 channels (H	ardware or software me	ode can be selected.)				
D/A converter (PWM) 3 channels (8-bit or 9-bit resolution, selected by software.) Output frequency: 4.4 kHz, 440 Hz (8-bit PWM) 2.2 kHz, 220 Hz (9-bit PWM)								
Seria	ıl interface	2 systems (4 channels) Selectable for 3-wire serial I/O method, SBI method, 2-wire serial I/O method, or I ² C bus methodNote. Selectable for 3-wire serial I/O method or UART method.						
PLL	Frequency division system	Direct frequency div Pulse swallow system		n (MF mode) : 0.5 to n (HF mode) : 10 to in (VHF mode): 60 to	40 MHz)			
	Reference frequency		Can be set to one of 13 frequencies (1, 1.25, 2.5, 3, 5, 6.25, 9, 10, 12.5, 18, 20, 25, or 50 kHz).					
	Charge pump	2 error output pins (E	O0 and EO1)					
Phase comparator Unlock detection is enabled by software.								
Intermediate frequency counter		Intermediate frequency (IF) measurement P1C0/FMIFC pin : 10 to 11 MHz in FMIF mode						
		 External gate width P2A1/FCG1 and P2 						

Note When ordering a mask, please consult our sales office if the I²C bus method is used (or when the serial interface is accomplished by the program not by the peripheral hardware).



(2/2)

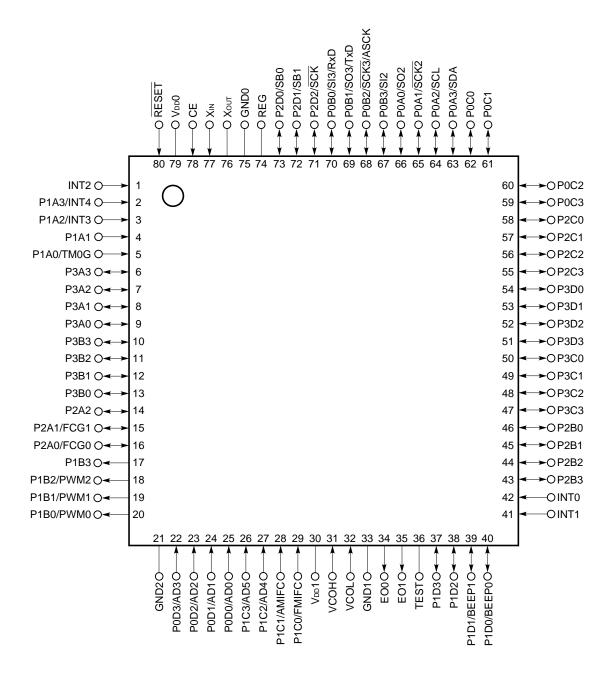
Product	μPD17717	μPD17718	μPD17719	μPD17P719	
BEEP output		Hz, 3 kHz, 4 kHz, 6.7 kH Hz, 200 Hz, 3 kHz, 4 kH	` ' '		
Reset	 Power-on reset (when the power is turned on) Reset using the RESET pin Watchdog timer reset Can be set only once at power-on: 65,536 instructions, 131,072 instructions, or non-use can be selected. Stack pointer overflow/underflow reset Can be set only once at power-on: the interrupt stack or address stack can be selected. CE reset (CE pin: low → high) A CE reset delay timing can be set. Power-failure detection function 			·	
Standby	Clock stop mode (STOP) Halt mode (HALT)				
Supply voltage	 PLL operation: V_{DD} = 4.5 to 5.5 V CPU operation: V_{DD} = 3.5 to 5.5 V 				
Package	80-pin plastic QFP (14	\times 14 mm, 0.65-mm pitch	h)		



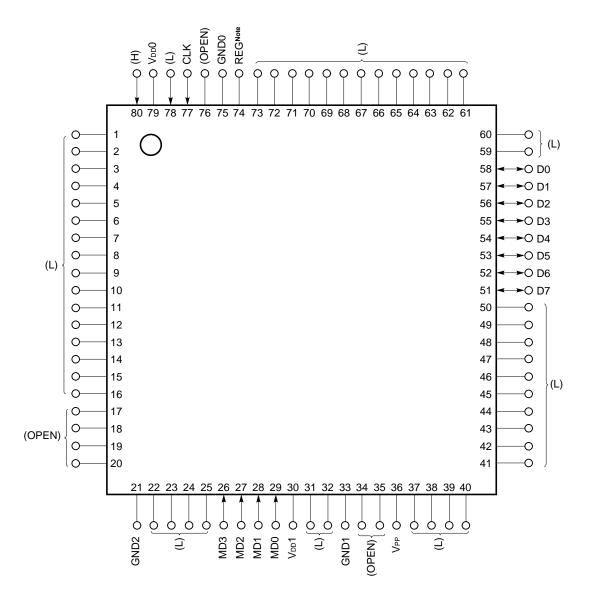
PIN CONFIGURATION (TOP VIEW)

80-pin plastic QFP (14 \times 14 mm, 0.65-mm pitch) μ PD17P719GC-3B9

(1) Normal operation mode



(2) PROM programming mode



Note Connect to the same potential as VDD.

Caution The parentheses above indicate the handling of the pins not used in PROM programming mode.

L : Connect each pin to GND through a resistor (470 ohms).

H: Connect each pin to VDD through a resistor (470 ohms).

OPEN: Leave each pin open.



PIN NAMES

AD0-AD5 : A/D converter inputs P2C0-P2C3 : Port 2C **AMIFC** : AM frequency counter input : Port 2D P2D0-P2D2 ASCK : UART serial clock I/O P3A0-P3A3 : Port 3A BEEP0, BEEP1: Beep outputs P3B0-P3B3 : Port 3B CE : Chip enable P3C0-P3C3 : Port 3C CLK : Address update clock input P3D0-P3D3 : Port 3D D0-D7 : Data I/O REG

: CPU regulator : Error outputs RESET : Reset input EO0, EO1

: Frequency counter gate inputs : UART serial data input FCG0, FCG1 RxD**FMIFC** : FM frequency counter input SB0, SB1 : SBI serial data I/O SCK : SBI serial clock I/O GND0-GND2 : Ground 0 to 2 SCK2, SCK3 : 3-wire serial clock I/O INT0-INT4 : External interrupt inputs : Operating mode selection SCL : 2-wire serial clock I/O MD0-MD3 PWM0-PWM2 : D/A converter outputs SDA : 2-wire serial data I/O

P0A0-P0A3 : Port 0A SI2, SI3 : 3-wire serial data input P0B0-P0B3 : Port 0B SO2, SO3 : 3-wire serial data output

P0C0-P0C3 : Port 0C **TEST** : Test input

P0D0-P0D3 : Port 0D TM0G : Timer 0 gate input P1A0-P1A3 : Port 1A TxD : UART serial data output

VCOH P1B0-P1B3 : Port 1B : Local oscillation high input P1C0-P1C3 : Port 1C VCOL : Local oscillation low input

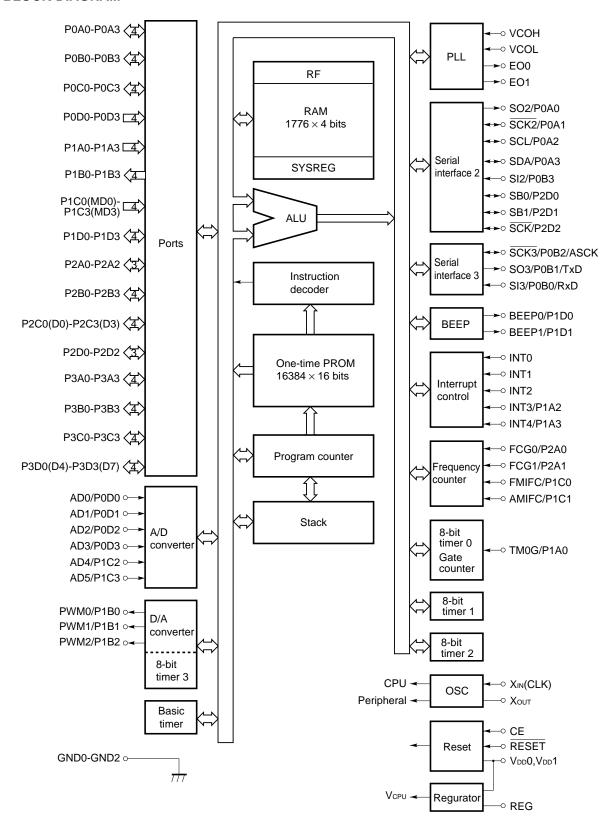
: Port 1D VDDO, VDD1 : Power supply P1D0-P1D3

P2A0-P2A2 : Port 2A V_{PP} : Program voltage application

P2B0-P2B3 : Port 2B XIN, XOUT : Main clock oscillation



BLOCK DIAGRAM



Remark Pins enclosed in parentheses are used in PROM programming mode.



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1. PIN FUNCTIONS

1.1 NORMAL OPERATION MODE

Pin No.	Symbol		Function			Output format		
1 41 42	INT2 INT1 INT0	Input for edge-de can be selected.	Input for edge-detected vectored. Either a rising edge or falling edge can be selected.					
2 3 4 5	P1A3/INT4 P1A2/INT3 P1A1 P1A0/TM0G	 P1A3-P1A0 4-bit input po INT4, INT3 Edge-detect TM0G 	4-bit input portINT4, INT3Edge-detected vectored interrupt					
			When reset		When the clock			
		Power-on reset	WDT&SP reset	CE reset	is stopped			
		Input (P1A3-P1A0)	Input (P1A3-P1A0)	Held	Held			
6 to	P3A3 to	4-bit I/O port. Input/output can be specified in 4-bit units.				CMOS push-pull		
9	P3A0		When reset		When the clock			
		Power-on reset	WDT&SP reset	CE reset	is stopped			
		Input	Input	Held	Held			
10 to	P3B3 to	4-bit I/O port. Input/output can I	be specified in 4-bit	units.		CMOS push-pull		
13	P3B0		When reset		When the clock			
		Power-on reset	WDT&SP reset	CE reset	is stopped			
		Input	Input	Held	Held			
14 15 16	P2A2 P2A1/FCG1 P2A0/FCG0 P2A0/FCG0 Input for port 2A and external gate counter P2A2-P2A0 P2A0/FCG0 3-bit I/O port Input/output can be specified bit by bit. FCG1, FCG0 External gate counter input			CMOS push-pull				
			When reset		When the clock	1		
		Power-on reset	WDT&SP reset	CE reset	is stopped			
		Input (P2A2-P2A0)	Input (P2A2-P2A0)	Held (P2A2-P2A0)	Held (P2A2-P2A0)			



Pin No.	Symbol		Function						
17 18 to 20	P1B3 P1B2/PWM2 to P1B0/PWM0	P1B3-P1B04-bit output pPWM2-PWM0	 4-bit output port PWM2-PWM0 8-bit or 9-bit D/A converter output 			P1B3-P1B04-bit output portPWM2-PWM0			N-ch open-drain (12-V withstand voltage)
		Power-on reset	WDT&SP reset	CE reset	is stopped				
		Low-level output (P1B3-P1B0)	Low-level output (P1B3-P1B0)	Held	Held (P1B3-P1B0)				
21 33 75	GND2 GND1 GND0	Ground				-			
22 to 25	P0D3/AD3 to P0D0/AD0	P0D3-P0D04-bit input poA pull-down rAD3-AD0	4-bit input portA pull-down resistor can be set bit by bit.						
			When reset						
		Power-on reset	WDT&SP reset	CE reset	is stopped				
		Input with pull- down resistors (P0D3-P0D0)	Input with pull- down resistors (P0D3-P0D0)	Held	Held				
26	P1C3/AD5	Input for port 1C,	A/D converter, and	IF counter		-			
27	P1C2/AD4	• P1C3-P1C0							
28	P1C1/AMIFC	4-bit input po	rt						
29	• AD5, AD4								
			When reset		When the clock				
		Power-on reset	WDT&SP reset	CE reset	is stopped				
		Input (P1C3-P1C0)	(P1C3-P1C0)	P1C3/AD5, P1C2/AD4 Held P1C1/AMIFC, P1C0/FMIFC Input (P1C1, P1C0)	 P1C3/AD5, P1C2/AD4 Held P1C1/AMIFC, P1C0/FMIFC Input (P1C1, P1C0) 				



Pin No.	Symbol		Fur	nction		Output format	
30 79	V _{DD} 1 V _{DD} 0	When the CF When only the	 Power supply. Apply the same voltage to the V_{DD}1 and V_{DD}0 pins. When the CPU and peripheral functions are operating: 4.5 to 5.5 V When only the CPU is operating: 3.5 to 5.5 V When the clock is stopped: 2.2 to 5.5 V 				
31 32	VCOH VCOL	VCOH Active when down. VCOL Active when pulled down.	 Active when VHF mode is selected by software. Otherwise, pulled down. VCOL Active when HF or MW mode is selected by software. Otherwise, pulled down. Inputs to these pins are to be AC-amplified. Cut, therefore, the DC				
34 35	EO0 EO1	result of phase co	harge pump of the omparison between ence frequency is	the divided local	•	CMOS tristate	
			When reset		When the clock		
		Power-on reset	WDT&SP reset	CE reset	is stopped		
		High-impedance output	High-impedance output	High-impedance output	High-impedance output		
36	TEST	Test input pin. Be sure to connect	ct it to GND.			-	
37 38 39 40	P1D3 P1D2 P1D1/BEEP1 P1D0/BEEP0	Output for port 1E P1D3-P1D0 4-bit I/O port Input/output of BEEP1, BEEP0 BEEP output	can be specified b	it by bit.		CMOS push-pull	
			When reset		When the clock		
		Power-on reset	WDT&SP reset	CE reset	is stopped		
		Input (P1D3-P1D0)	Input (P1D3-P1D0)	Held (P1D3-P1D0)	Held (P1D3-P1D0)		
43 to	P2B3 to	4-bit I/O port. Input/output can b	ne specified bit by	bit.		CMOS push-pull	
46	P2B0		When reset		When the clock		
		Power-on reset	WDT&SP reset	CE reset	is stopped		
		Input	Input	Held	Held		
47 to	P3C3 to	4-bit I/O port. Input/output can be specified in 4-bit units.				CMOS push-pull	
50	P3C0		When reset		When the clock		
		Power-on reset	WDT&SP reset	CE reset	is stopped		
		Input	Input	Held	Held		



Pin No.	Symbol		Function			Output format
51	P3D3	4-bit I/O port.				CMOS push-pull
to	to	Input/output can b	Input/output can be specified in 4-bit units.			
54	P3D0		When reset		When the clock	
		Power-on reset	WDT&SP reset	CE reset	is stopped	
		Input	Input	Held	Held	
55	P2C3	4-bit I/O port.	I	I	I	CMOS push-pull
to	to	Input/output can b	e specified bit by b	it.		
58	P2C0		When reset		When the clock	
		Power-on reset	WDT&SP reset	CE reset	is stopped	
			Input	Held	Held	
59	P0C3	Input	Input	пеіа	Tield	CMOS push-pull
to	to	4-bit I/O port.	and the second second second	••		CiviO3 pusii-puii
62	P0C0	input/output can i	be specified bit by b	It.	1	
			When reset		When the clock	
		Power-on reset	WDT&SP reset	CE reset	is stopped	
		Input	Input	Held	Held	
63	P0A3/SDA	1 1	0A, P0B, P2D, and	serial interface		N-ch open-drain
64	P0A2/SCL	• P0A3-P0A0				
65	P0A1/SCK2	4-bit I/O port	can be specified bit	by bit		CMOS push-pull
66	P0A0/SO2	• P0B3-P0B0	can be specified bit	by bit.		
67	P0B3/SI2	• 4-bit I/O port				
68	P0B2/SCK3/		can be specified bit	by bit.		
	ASCK	• P2D2-P2D0				
69	P0B1/SO3/TxD	• 3-bit I/O port				
			can be specified bit	by bit.		
70	P0B0/SI3/RxD	SDA, SCL Serial data a	nd serial clock I/O v	when the 2-wire	serial I/O or I ² C bus	
71	P2D2/SCK		face 2 is selected.	WHOTI THE Z WHO		
72	P2D1/SB1	• SCK2, SO2, SI	2			N-ch open-drain
73	P2D0/SB0	Serial clock I	O, serial data outp	ut, and serial da	ata input when the	
			I/O of serial interfac	e 2 is selected.		
		SCK3, SO3, SI			de Seast orbres des	
			O, serial data outp I/O of serial interfac			
		ASCK, TxD, Rx		e 3 is selected.		
			/O, serial data outp	ut, and serial da	ata input when the	
			al interface 3 is sel		•	
		• SCK, SB1, SB0)			
			and serial data I/O v	when the SBI of	serial interface 2 is	
		selected.			T	
			When reset		When the clock	
		Power-on reset	WDT&SP reset	CE reset	is stopped	
		Input	Input	Held	Held	
		P0A3-P0A0,	P0A3-P0A0,	P0A3-P0A0,	P0A3-P0A0,	
		P0B3-P0B0,	P0B3-P0B0,	P0B3-P0B0,	P0B3-P0B0,	
		P2D2-P2D0	P2D2-P2D0	P2D2-P2D0	P2D2-P2D0	



Pin No.	Symbol	Function	Output format
74	REG	CPU regulator. Use 0.1-μF capacitor to connect it to GND.	-
76 77	Xout Xin	A crystal is connected to these pins.	-
78	CE	 Input for device operation selection, CE reset, and interrupt signals Device operation selection When CE is high, the PLL frequency synthesizer can be operated. When CE is low, the PLL frequency synthesizer is automatically disabled by the device. CE reset Setting CE from low to high resets the device upon the detection of a rising edge of the internal basic timer setting pulse. A reset timing delay can also be specified. Interrupt A vectored interrupt occurs upon the detection of a falling edge of the input signal. 	-
80	RESET	Reset input	-

1.2 PROM PROGRAMMING MODE

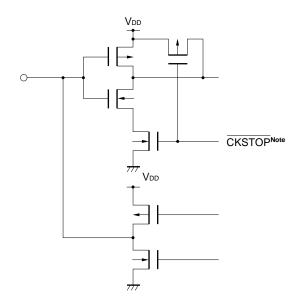
Pin No.	Symbol	Function	Output format
26 to 29	MD3 to MD0	Input for operating mode selection for program memory write, read, or verification	-
21 33 75	GND2 GND1 GND0	Ground	-
36	VPP	Pin to which program voltage is applied during program memory write, read, or verification. +12.5 V is applied.	-
30 79	V _{DD} 1 V _{DD} 0	Power supply pins. +6 V is applied during program memory write, read, or verification.	-
51 to 58	D7 to D0	8-bit data I/O for program memory write, read, or verification	CMOS push-pull
77	CLK	Clock input for address updating during program memory write, read, or verification	-

Remark The pins other than those listed above are not used in PROM programming mode. For the handling of the unused pins, see **PIN CONFIGURATION**, **(2) PROM programming mode**.



1.3 EQUIVALENT CIRCUIT OF PINS

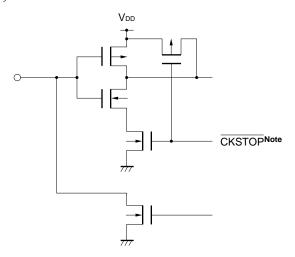
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(1) P0A (P0A1/SCK2, P0A0/SO2)
P0B (P0B3/SI2, P0B2/SCK3/ASCK, P0B1/SO3/TxD, P0B0/SI3/RxD)
P0C (P0C3, P0C2, P0C1, P0C0)
P1D (P1D3, P1D2, P1D1/BEEP1, P1D0/BEEP0)
P2A (P2A2, P2A1/FCG1, P2A0/FCG0)
P2B (P2B3, P2B2, P2B1, P2B0)
P2C (P2C3, P2C2, P2C1, P2C0)
P2D (P2D2/SCK)
P3A (P3A3, P3A2, P3A1, P3A0)
P3B (P3B3, P3B2, P3B1, P3B0)
P3C (P3C3, P3C2, P3C1, P3C0)
P3D (P3D3, P3D2, P3D1, P3D0)
```



Note In this circuit, a current drained by noise does not increase even if the circuit is in the floating state, because of the internal signal being output when the clock stop instruction is executed.

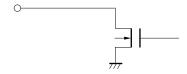


(2) P0A (P0A3/SDA, P0A2/SCL) P2D (P2D1/SB1, P2D0/SB0) (I/O)

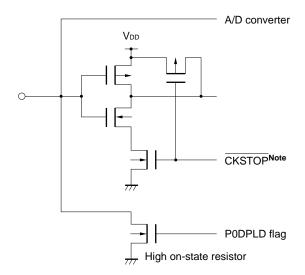


Note In this circuit, a current drained by noise does not increase even if the circuit is in the floating state, because of the internal signal being output when the clock stop instruction is executed.

(3) P1B (P1B3, P1B2/PWM2, P1B1/PWM1, P1B0/PWM0) (Output)



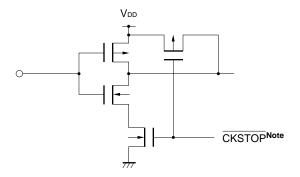
(4) P0D (P0D3/AD3, P0D2/AD2, P0D1/AD1, P0D0/AD0) (Input)



Note In this circuit, a current drained by noise does not increase even if the circuit is in the floating state, because of the internal signal being output when the clock stop instruction is executed.

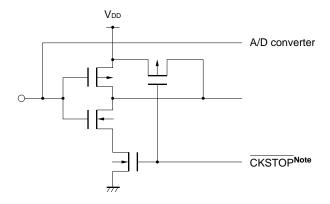


(5) P1A (P1A1) (Input)



Note In this circuit, a current drained by noise does not increase even if the circuit is in the floating state, because of the internal signal being output when the clock stop instruction is executed.

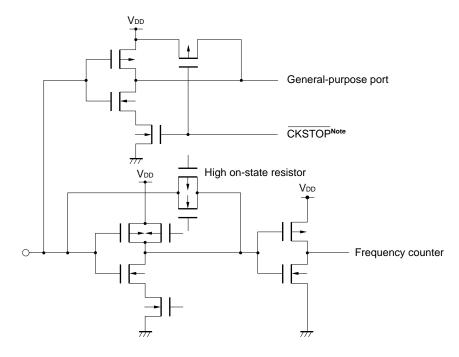
(6) P1C (P1C3/AD5, P1C2/AD4) (Input)



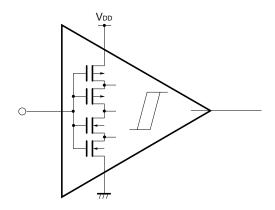
Note In this circuit, a current drained by noise does not increase even if the circuit is in the floating state, because of the internal signal being output when the clock stop instruction is executed.



(7) P1C (P1C1/AMIFC, P1C0/FMIFC) (Input)

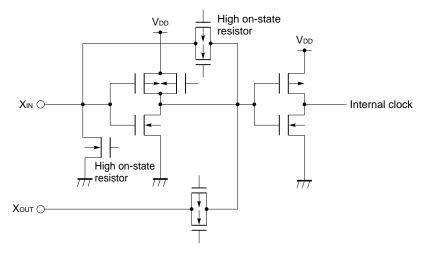


Note In this circuit, a current drained by noise does not increase even if the circuit is in the floating state, because of the internal signal being output when the clock stop instruction is executed.

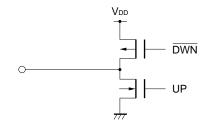




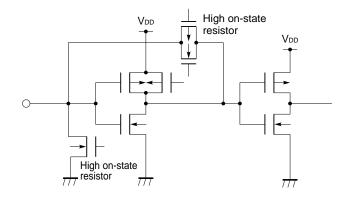
(9) XOUT (Output), XIN (Input)



(10) EO1, EO0 (Output)



(11) VCOH, VCOL (Input)





1.4 HANDLING UNUSED PINS

The unused pins should be handled as indicated in Table 1-1.

Table 1-1 Handling Unused Pins

(1/2)

	Pin	I/O format	Recommended handling
	P0D3/AD3-P0D0/AD0	Input	Connect each pin to GND through a resistor. Note 1
	P1C3/AD5 P1C2/AD4 P1C1/AMIFCNote 2 P1C0/FMIFCNote 2		Specify as a port and connect each pin to VDD or GND through a resistor. Note 1
	P1A3/INT4 P1A2/INT3 P1A1 P1A0/TM0G		Connect each pin to GND through a resistor.Note 1
	P1B3 P1B2/PWM2-P1B0/PWM0	N-ch open-drain output	Specify low output, in the software, and leave open.
Port pins	P0A3/SDA P0A2/SCL P0A1/SCK2 P0A0/SO2	I/ONote 3	Specify as a general-purpose input port, in the software, and connect each pin to VDD or GND through a resistor. Note 1
Por	P0B3/SI2 P0B2/SCK3/ASCK P0B1/SO3/TxD P0B0/SI3/RxD		
	P0C3-P0C0		
	P1D3 P1D2 P1D1/BEEP1 P1D0/BEEP0		
	P2A2 P2A1/FCG1 P2A0/FCG0		
	P2B3-P2B0 P2C3-P2C0		

- **Notes 1.** When making an external connection to VDD with a pull-up resistor, or to GND with a pull-down resistor, note the following: If the resistance of the pull-up or pull-down resistor is too high, the pin approaches the high impedance state, thus increasing the through current drawn by the port. In general, pull-up and pull-down resistors should have a resistance of between 20 and 50 kilohms, depending on the application circuit.
 - 2. Do not specify AMIFC or FMIFC. If AMIFC or FMIFC is specified, current drain increases.
 - **3.** I/O ports become general-purpose input ports upon power-on reset, reset by the RESET pin, watchdog timer reset, or stack overflow/underflow reset.



Table 1-1 Handling Unused Pins

(2/2)

	Pin	I/O format	Recommended handling
S	P2D2/SCK P2D1/SB1 P2D0/SB0	I/ONote 2	Specify as a general-purpose input port, in the software, and connect each pin to VDD or GND through a resistor. Note 1
t pins	P3A3-P3A0		
Port	P3B3-P3B0		
	P3C3-P3C0		
	P3D3-P3D0		
	CE	Input	Connect to VDD through a resistor. Note 1
pins	EO1 EO0	Output	Leave each pin open.
port	INT0-INT2	Input	Connect each pin to GND through a resistor. Note 1
than	RESET	Input	Connect to VDD through a resistor. Note 1
Other t	TEST	-	Connect directly to GND.
ď	VCOH VCOL	Input	Disable PLL, in the program, and leave each pin open.

- **Notes 1.** When making an external connection to VDD with a pull-up resistor, or to GND with a pull-down resistor, note the following: If the resistance of the pull-up or pull-down resistor is too high, the pin approaches the high impedance state, thus increasing the through current drawn by the port. In general, pull-up and pull-down resistors should have a resistance of between 20 and 50 kilohms, depending on the application circuit.
 - 2. I/O ports become general-purpose input ports upon power-on reset, reset by the RESET pin, watchdog timer reset, or stack overflow/underflow reset.



1.5 NOTES ON USE OF THE CE, INTO-INT4, AND RESET PINS (ONLY IN NORMAL OPERATION MODE)

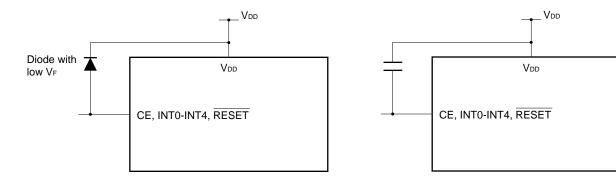
The CE, INT0-INT4, and \overline{RESET} pins can be used as the test mode selection pin for testing the internal operation of the μ PD17P719 (IC test), besides the usage shown in **Section 1.1**.

Applying a voltage exceeding V_{DD} to the CE, INT0-INT4, or RESET pin causes the μ PD17P719 to enter test mode. When noise exceeding V_{DD} comes in during normal operation, the device may not operate normally.

For example, if the wiring from the CE, INT0-INT4, or RESET pin is too long, noise may be induced on the wiring, causing this mode switching.

When installing the wiring, lay the wiring in such a way that noise is suppressed as much as possible. If noise yet arises, use an external part to suppress it as shown below.

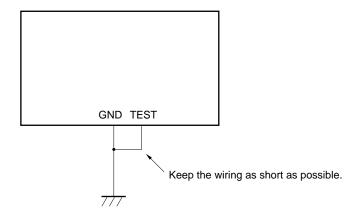
 Connect a diode with low V_F between the pin and V_{DD}. Connect a capacitor between the pin and VDD.



1.6 NOTES ON USE OF THE TEST PIN (ONLY IN NORMAL OPERATION MODE)

Applying V_{DD} to the TEST pin causes the μ PD17P719 to enter test mode or program memory write/verify mode. Keep the wiring as short as possible and connect the TEST pin directly to the GND pin.

When the wiring between the TEST pin and GND pin is too long or external noise enters the TEST pin, a voltage difference may occur between the TEST pin and GND pin. When this happens, your program may malfunction.





2. ONE-TIME PROM (PROGRAM MEMORY) WRITE, READ, AND VERIFICATION

The program memory built into the μ PD17P719 is a one-time PROM (16384 × 16 bits) that is electrically writable. In normal operation, this PROM is accessed on a 16-bit word basis. During program memory write, read, and verification, the PROM is accessed on an 8-bit word basis. The higher 8 bits of a 16-bit word are located at an even-numbered address, and the lower 8 bits are located at an odd-numbered address.

For PROM write, read, and verification, PROM programming mode must be specified, and the pins listed in Table 2-1 are used

In this case, address input is not used. Instead, clock input on the CLK pin is used to update addresses.

Table 2-1 Pins Used for Program Memory Write, Read, and Verification

Pin	Function
V _{PP}	Used to apply the program voltage (+12.5 V)
CLK	Used to apply an address update clock
MD0-MD3	Used to select an operating mode
D0-D7	Used to input/output 8-bit data
VDDO, VDD1	Used to apply the power supply voltage (+6 V)

For writing to the built-in PROM, a specified PROM programmer and dedicated programmer adapter are to be used. The following PROM programmers and programmer adapters are usable:

PROM programmer	Programmer adapter
PG-1500	PA-17P709GC
+	
PA-17KDZ	
(adapter for PG-1500)	

Third-party PROM programmers are also available: For example, AF-9703, AF-9704, AF-9705, and AF-9706 (manufactured by Ando Electric Co., Ltd.)



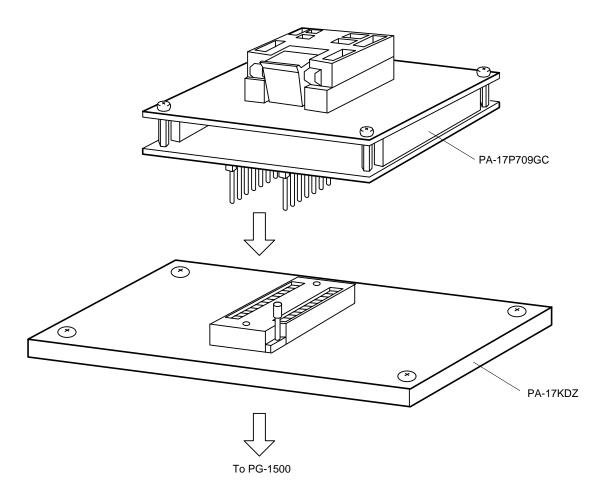


Fig. 2-1 PA17P709GC and PA-17KDZ

2.1 OPERATING MODES FOR PROGRAM MEMORY WRITE, READ, AND VERIFICATION

The μ PD17P719 is placed in program memory write, read, and verify mode when +6 V is applied to the V_{DD} pin, and +12.5 V to the V_{PP} pin.

In this mode, one of the operating modes indicated in Table 2-2 is set, depending on the setting of the MD0 to MD3 pins.

The input pins that are not used for program memory write, read, and verification are connected to GND through a pull-down resistor (470 ohms). (See **PIN CONFIGURATION**, **(2) PROM programming mode**.)

Table 2-2 Operating Modes for Program Memory Write, Read, and Verication

Operating mode specification						Operating mode			
VPP	V _{DD}	MD0	MD1	MD2	MD3	Operating mode			
+12.5 V	+6 V	Н	L	Н	L	Program memory address zero-clear mode			
		L	Н	Н	Н	Write mode			
		L	L	Н	Н	Read/verify mode			
		Н	Х	Н	Н	Program inhibit mode			

Remark X: L or H

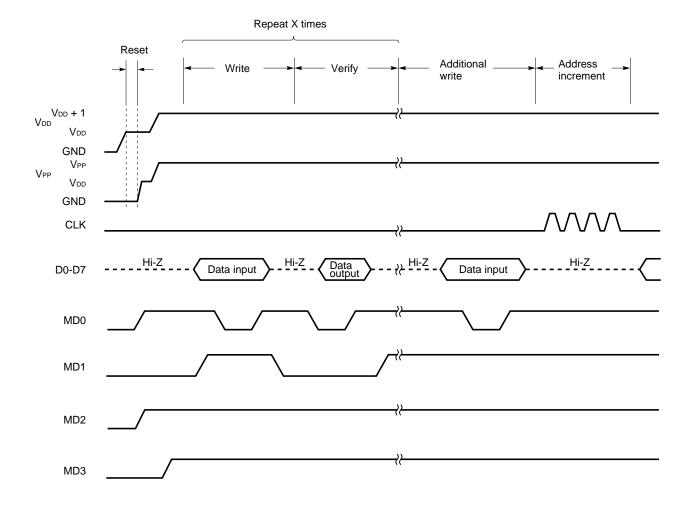


2.2 PROGRAM MEMORY WRITE PROCEDURE

The program memory write procedure is described below. The procedure allows high-speed write operation.

- (1) Connect the unused pins to GND through pull-down resistors. The CLK pin must be low.
- (2) Apply 5 V to the VDD pin. The VPP pin must be low.
- (3) Apply 5 V to the VPP pin after waiting 10 μ s.
- (4) Specify program memory address zero-clear mode, using the mode setting pins.
- (5) Apply 6 V to VDD, and 12.5 V to VPP.
- (6) Program inhibit mode
- (7) Write data in 1-ms write mode.
- (8) Program inhibit mode
- (9) Verify mode. When data has been written normally, proceed to step (10). When data has not been written normally, repeat steps (7) to (9).
- (10) Perform an additional write operation ((X: Number of write operations performed in steps (7) to (9)) \times 1 ms).
- (11) Program inhibit mode
- (12) Apply four pulses to the CLK pin to increment the program memory address by 1.
- (13) Repeat steps (7) to (12) until the last address is reached.
- (14) Program memory address zero-clear mode
- (15) Change the voltage applied to the VDD and VPP pins to 5 V.
- (16) Turn off the power.

Steps (2) to (12) are illustrated below.

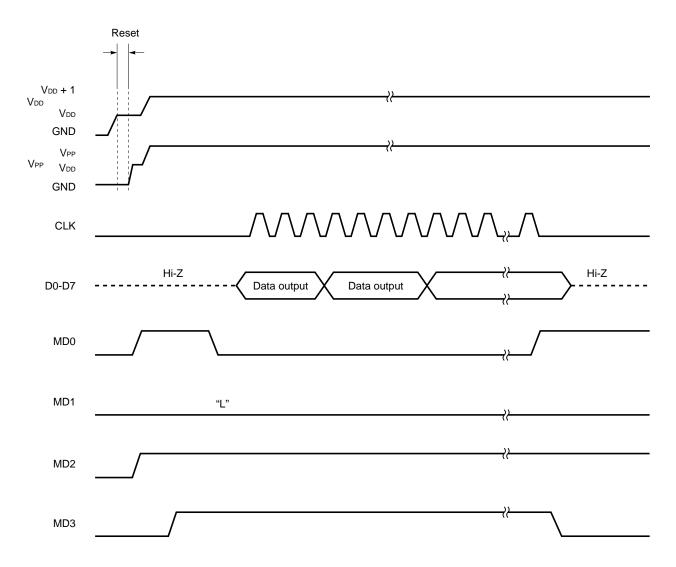




2.3 PROGRAM MEMORY READ PROCEDURE

- (1) Connect the unused pins to GND through pull-down resistors. The CLK pin must be low.
- (2) Apply 5 V to the VDD pin. The VPP pin must be low.
- (3) Apply 5 V to the VPP pin after waiting 10 μ s.
- (4) Specify program memory address zero-clear mode, using the mode setting pins.
- (5) Apply 6 V to VDD, and 12.5 V to VPP.
- (6) Program inhibit mode
- (7) Verify mode. When a clock pulse signal is applied to the CLK pin, data is output for each address every four clock pulses.
- (8) Program inhibit mode
- (9) Program memory address zero-clear mode
- (10) Change the voltage applied to the V_{DD} and V_{PP} pins to 5 V.
- (11) Turn off the power.

Steps (2) to (9) are illustrated below.





3. ELECTRICAL CHARACTERISTICS

ABSOLUTE MAXIMUM RATINGS (TA = 25 °C)

Parameter	Symbol	Condition	Rating	Unit
Supply voltage	V _{DD}		-0.3 to +6.0	V
PROM program voltage	V _{PP}		-0.3 to +13.5	V
Input voltage	Vı	At other than CE, INT0-INT4, and RESET pins	-0.3 to V _{DD} + 0.3	V
		CE, INT0-INT4, and RESET pins	-0.3 to V _{DD} + 0.6	V
Output voltage	Vo	At other than P1B0-P1B3	-0.3 to V _{DD} + 0.3	V
High output current	Іон	At one pin	-8.0	mA
		Total for P2A0-P2A2, P3A0-P3A3, and P3B0-P3B3	-15.0	mA
		Total for P0A0, P0A1, P0B0-P0B3, P0C0-P0C3, P1D0-P1D3, P2B0-P2B3, P2C0-P2C3, P2D2, P3C0-P3C3, and P3D0-P3D3	-25.0	mA
Low output current	Іоь	At one pin of P1B0-P1B3	12.0	mA
		At one pin of other than P1B0-P1B3	8.0	mA
		Total for P2A0-P2A2, P3A0-P3A3, and P3B0-P3B3	15.0	mA
		Total for P0A0-P0A3, P0B0-P0B3, P0C0-P0C3, P1D0-P1D3, P2B0-P2B3, P2C0-P2C3, P2D0-P2D2, P3C0-P3C3, and P3D0-P3D3	25.0	mA
		Total for P1B0-P1B3	25.0	mA
Output withstand voltage	V _{BDS}	P1B0-P1B3	14.0	V
Total loss	Pt		200	mW
Operating ambient temperature	Та		-40 to +85	°C
Storage temperature	Tstg		-55 to +125	°C

Caution Absolute maximum ratings are rated values beyond which physical damage will be caused to the product; if the rated value of any of the parameters in the above table is exceeded, even momentarily, the quality of the product may deteriorate. Always use the product within its rated values.

RECOMMENDED OPERATING RANGES (TA = -40 to +85 °C)

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Supply voltage	V _{DD1}	While the CPU and PLL are operating	4.5	5.0	5.5	V
	V _{DD2}	While the CPU is operating but the PLL is halted	3.5	5.0	5.5	V

RECOMMENDED OUTPUT WITHSTAND VOLTAGE (TA = -40 to +85 °C)

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Output withstand voltage	V _{BDS}	P1B0-P1B3			12	V



DC CHARACTERISTICS (TA = -40 to +85 $^{\circ}$ C, VDD = 3.5 to 5.5 V)

Parameter	Symbol		Condition	Min.	Тур.	Max.	Unit
Supply current	I _{DD1}	The CPU is operating bu sinusoidal wave applied (fin = 4.5 MHz ±1%, Vin =			1.5	3.0	mA
	I _{DD2}	The CPU and PLL are had applied to the X_{IN} pin. ($f_{IN} = 4.5 \text{ MHz} \pm 1\%, V_{IN} = 1\%$) The HALT instruction is the			0.7	1.5	mA
Data hold voltage	V _{DDR1}	The crystal oscillator is o	3.5		5.5	V	
	V _{DDR2}	The crystal oscillator is halted.	The timer flip-flop is used for detecting power failure.	2.2		5.5	V
	V _{DDR3}		Data memory contents are held.	2.0		5.5	V
Data hold current	I _{DDR1}	The crystal oscillator is	V _{DD} = 5 V, T _A = 25 °C		2.0	4.0	μΑ
	IDDR2	halted.			2.0	30.0	μΑ
High input voltage	V _{IH1}	· '	3, P1A0, P1A1, P1C0-P1C3, 0-P2B3, P2C0-P2C3, P3A0-P3A3, 5, P3D0-P3D3	0.7V _{DD}		V _{DD}	V
	V _{IH2}	P0A1-P0A3, P0B0, P0B2 P2D0-P2D2, CE, INT0-IN	0.8V _{DD}		V _{DD}	V	
	VIH3	P0D0-P0D3	0.55V _{DD}		V _{DD}	V	
Low input voltage	VIL1	P0A0, P0B1, P0C0-P0C3 P1D0-P1D3, P2A2, P2B0 P3B0-P3B3, P3C0-P3C3	0		0.3V _{DD}	V	
	V _{IL2}	P0A1-P0A3, P0B0, P0B2 P2D0-P2D2, CE, INT0-IN	0		0.2V _{DD}	V	
	V _{IL3}	P0D0-P0D3		0		0.15V _{DD}	V
High output current	Іон1	P2A0-P2A2, P2B0-P2B3	3, P0C0-P0C3, P1D0-P1D3, , P2C0-P2C3, P2D2, , P3C0-P3C3, P3D0-P3D3 Vон = Vpp - 1 V	-1.0			mA
	І он2	EO0, EO1 V _D	D = 4.5 to 5.5 V, VoH = VDD - 1 V	-3.0			mA
Low output current	IOL1	P2A0-P2A2, P2B0-P2B3	, P0C0-P0C3, P1D0-P1D3, , P2C0-P2C3, P2D0-P2D2, , P3C0-P3C3, P3D0-P3D3	1.0			mA
	lo _{L2}	EO0, EO1	$V_{DD} = 4.5 \text{ to } 5.5 \text{ V}, V_{OL} = 1 \text{ V}$	3.0			mA
	І оьз	P1B0-P1B3	Vol = 1 V	7.0			mA
High input current	Іін	P0D0-P0D3 are pulled do	own. $V_{IN} = V_{DD}$	5.0		150	μΑ
Output-off leakage	ILO1	P1B0-P1B3	V _{IN} = 12 V			1.0	μΑ
current	ILO2	EO0, EO1	$V_{IN} = V_{DD}, V_{IN} = 0 V$			±1.0	μΑ
High input leakage current	Ішн	Input pin	$V_{IN} = V_{DD}$			1.0	μΑ
Low input leakage current	ILIL	Input pin	VIN = 0 V			-1.0	μΑ



AC CHARACTERISTICS (TA = -40 to +85 °C, VDD = 5 V $\pm 10\%$)

Parameter	Symbol		Condition	Min.	Тур.	Max.	Unit
Operating frequency	f _{IN1}	VCOL pin in MF mode	Sinusoidal wave applied to the VIN pin = 0.15V _{P-P}	0.8		3	MHz
			Sinusoidal wave applied to the V _{IN} pin = 0.20V _{P-P}	0.5		3	MHz
	f _{IN2}	VCOL pin in HF mode, the V_{IN} pin = $0.1V_{p-p}$ Note	with a sinusoidal wave applied to	10		40	MHz
	fınз	VCOH pin in VHF mode the V _{IN} pin = 0.1V _{p-p} Note	e, with a sinusoidal wave applied to	60		130	MHz
	fin4	AMIFC pin, with a sinus	soidal wave applied to the	0.4		0.5	MHz
	f _{IN5}	FMIFC pin in FMIF cou applied to the V _{IN} pin =	nt mode, with a sinusoidal wave $0.20V_{P-P}$	10		11	MHz
	fin6	FMIFC pin in AMIF count mode, with a sinusoidal wave applied to the V_{IN} pin = $0.15V_{P-P}$		0.4		0.5	MHz
SIO2 input frequency	f _{IN7}	External clock				1	MHz
SIO3 input frequency	fin8	External clock				0.7	MHz

Note The condition of sinusoidal wave input $V_{IN} = 0.1 V_{p-p}$ is the rated value when the $\mu PD17P719$ alone is operating. Where influence of noise must be taken into consideration, operation under input amplitude condition of $V_{IN} = 0.15 V_{p-p}$ is recommended.

A/D CONVERTER CHARACTERISTICS (TA = -40 to +85 $^{\circ}$ C, VDD = 5 V $\pm 10\%$)

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Total error in A/D conversion		8 bits			±3.0	LSB
Total error in A/D conversion		8 bits $T_A = 0$ to 85 °C			±2.5	LSB

REFERENCE CHARACTERISTICS (TA = +25 °C, VDD = 5.0 V)

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Supply current	I _{DD3}	The CPU and PLL are operating, with a sinusoidal wave applied to the VCOH pin. $(f_{IN}=130~MHz,~V_{IN}=0.3V_{p\text{-}p})$		6.0	12.0	mA



DC PROGRAMMING CHARACTERISTICS (TA = 25 ± 5 °C, VDD = 6.0 ± 0.25 V, VPP = 12.5 ± 0.3 V)

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Input high voltage	V _{IH1}	Other than CLK	0.7V _{DD}		V _{DD}	٧
	V _{IH2}	CLK	V _{DD} - 0.5		V _{DD}	V
Input low voltage	VIL1	Other than CLK	0		0.3V _{DD}	V
	V _{IL2}	CLK	0		0.4	V
Input leakage current	Iu	VIN = VIL OF VIH			10	μΑ
Output high voltage	Vон	Iон = -1 mA	V _{DD} -1.0			V
Output low voltage	Vol	IoL = 1.6 mA			0.4	V
V _{DD} supply current	IDD				30	mA
VPP supply current	Ірр	MD0 = VIL, MD1 = VIH		-	30	mA

Cautions 1. VPP must be under +13.5 V including overshoot.

2. VDD must be applied before VPP on and must be off after VPP off.

AC PROGRAMMING CHARACTERISTICS (TA = 25 ± 5 °C, Vdd = 6.0 ± 0.25 V, Vpp = 12.5 ± 0.3 V)

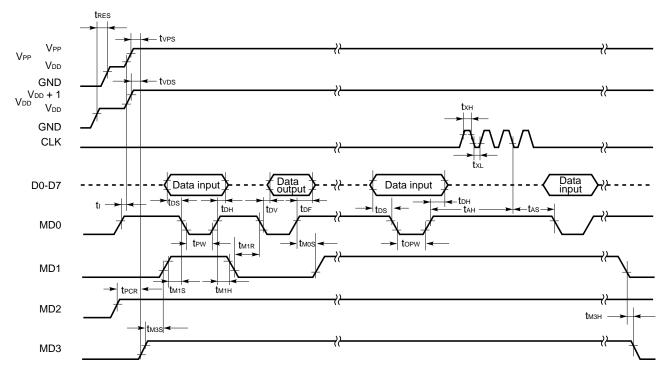
Parameter	Symbol	Note 1	Condition	Min.	Тур.	Max.	Unit
Address setup timeNote 2 (referred to MD0↓)	tas	tas		2			μs
MD1 setup time (referred to MD0↓)	t _{M1S}	toes		2			μs
Data setup time (referred to MD0↓)	tos	tos		2			μs
Address hold timeNote 2 (referred to MD0↑)	tан	t AH		2			μs
Data hold time (referred to MD0↑)	tон	tон		2			μs
Data output float delay from MD0↑	tof	tof		0		130	ns
V _{PP} setup time (referred to MD3 [↑])	tvps	tvps		2			μs
V _{DD} setup time (referred to MD3↑)	tvps	tvcs		2			μs
Initial program pulse width	tpw	tpw		0.95	1.0	1.05	ms
Additional program pulse width	topw	topw		0.95		21.0	ms
MD0 setup time (referred to MD1 [↑])	tmos	tces		2			μs
Data output delay from MD0↓	tov	tov	MD0 = MD1 = VIL			1	μs
MD1 hold time (referred to MD0↑)	t м1H	toeh	tм1H + tм1R ≥ 50 μs	2			μs
MD1 recovery time (referred to MD0↓)	t _{M1R}	tor		2			μs
Program counter reset time	tpcr	-		10			μs
CLK input high, low level range	txH,txL	-		0.125			μs
CLK input frequency	fx	-				4.19	MHz
Initial mode set time	tı	-		2			μs
MD3 setup time (referred to MD1 [↑])	tмзs	-		2			μs
MD3 hold time (referred to MD1↓)	tмзн	-		2			μs
MD3 setup time (referred to MD0↓)	tмзsr	-	When reading	2			μs
Data output delay from address incrementNote 2	t DAD	tacc	program memory			2	μs
Data output hold time from address incrementNote 2	thad	tон		0		130	ns
MD3 hold time (referred to MD0↑)	tмзнк	-		2			μs
Data output float delay from MD3↓	tofr	-				2	μs
Reset setup time	tres	-		10			μs

Notes 1. Symbols used for the μ PD27C256 (The μ PD27C256 is used only for maintenance.)

2. The internal address signal is incremented by 1 on the falling edge of the third clock (CLK) pulse, with four CLK pulses treated as one cycle. Internal addresses are not connected to pins.

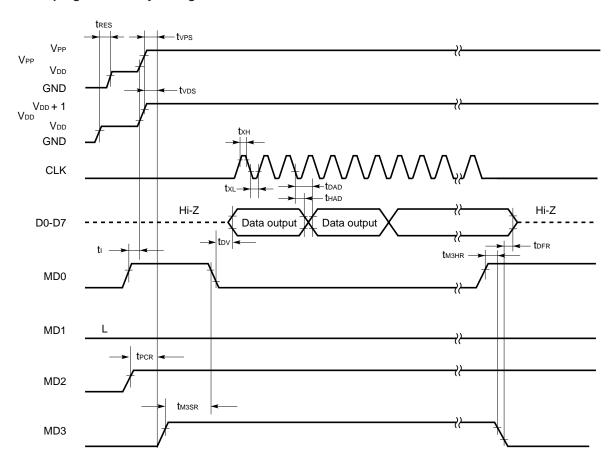


Write program memory timing



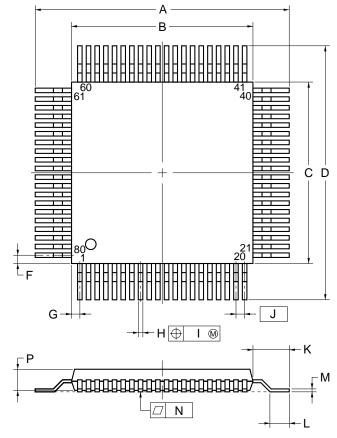
Remark The dashed line indicates high-impedance.

Read program memory timing

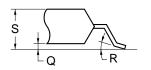


4. PACKAGE DRAWING

80 PIN PLASTIC QFP (14×14)



detail of lead end



NOTE

Each lead centerline is located within 0.13 mm (0.005 inch) of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS	INCHES		
Α	17.2±0.4	0.677±0.016		
В	14.0±0.2	0.551 ^{+0.009} _{-0.008}		
С	14.0±0.2	0.551+0.009		
D	17.2±0.4 0.677±0.016			
F	0.825	0.032		
G	0.825	0.032		
Н	0.30±0.10 0.012 ^{+0.00} _{-0.00}			
I	0.13	0.005		
J	0.65 (T.P.)	0.026 (T.P.)		
K	1.6±0.2	0.063±0.008		
L	0.8±0.2	0.031+0.009		
М	0.15 ^{+0.10} _{-0.05} 0.006 ^{+0.00} _{-0.00}			
N	0.10 0.004			
Р	2.7 0.106			
Q	0.1±0.1	0.004±0.004		
R	5°±5°	5°±5°		
S	3.0 MAX.	0.119 MAX.		

S80GC-65-3B9-4



5. RECOMMENDED SOLDERING CONDITIONS

The conditions listed below shall be met when soldering the μ PD17P719.

For details of the recommended soldering conditions, refer to our document *SMD Surface Mount Technology Manual* (C10535E).

Please consult with our sales offices in case any other soldering process is used, or in case soldering is done under different conditions.

Table 5-1 Soldering Conditions for Surface-Mount Devices

 μ PD17P719GC-3B9: 80-pin plastic QFP (14 \times 14 mm, 0.65-mm pitch)

Soldering process	Soldering conditions	Recommended conditions
Infrared ray reflow	Peak package's surface temperature: 235 °C Reflow time: 30 seconds or less (at 210 °C or more) Maximum allowable number of reflow processes: 3	IR35-00-3
VPS	Peak package's surface temperature: 215 °C Reflow time: 40 seconds or less (at 200 °C or more) Maximum allowable number of reflow processes: 3	VP15-00-3
Wave soldering	Solder temperature: 260 °C or less Flow time: 10 seconds or less Number of flow processes: 1 Preheating temperature: 120 °C max. (measured on the package surface)	WS60-00-1
Partial heating method	Terminal temperature: 300 °C or less Heat time: 3 seconds or less (for one side of a device)	-

Caution Do not apply more than a single process at once, except for "Partial heating method."



APPENDIX DEVELOPMENT TOOLS

The following support tools are available for developing programs for the μ PD17P719.

Hardware

Name	Description	
In-circuit emulator [IE-17K IE-17K-ETNote 1 EMU-17KNote 2	The IE-17K, IE-17K-ET, and EMU-17K are in-circuit emulators applicable to the 17K series. The IE-17K and IE-17K-ET are connected to the host machine (PC-9800 series or IBM PC/ATTM) through the RS-232C interface. The EMU-17K is inserted into the extension slot of the host machine (PC-9800 series). Use the system evaluation board (SE board) corresponding to each product together with one of these in-circuit emulators. <i>SIMPLEHOST</i> TM, a man machine interface, implements an advanced debug environment. The EMU-17K also enables user to check the contents of the data memory in real time.	
SE board (SE-17709)	The SE-17709 is an SE board for the μ PD17719 sub-series. It is used alone for evaluating the system. It is also used for debugging, in combination with an in-circuit emulator.	
Emulation probe (EP-17K80GC)	The EP-17K80GC is an emulation probe for the μ PD17P719GC. When used with the EV-9200GC-80Note 3, this emulation probe connects the SE board to the target system.	
Conversion socket (EV-9200GC-80 ^{Note 3})	The EV-9200GC-80 is a conversion socket for the 80-pin plastic QFP (14 \times 14 mm). It is used to connect the EP-17K80GC to the target system.	
PROM Programmer (PG-1500)	The PG-1500 is a PROM programmer for the μ PD17P719. Use this PROM programmer with the PA-17KDZ (adapter for the PG-1500) and PA-17P709GC programmer adapter, to program the μ PD17P719.	
Programmer adapter (PA-17P709GC)	The PA-17P709GC is a socket unit for the μ PD17P719. It is used with the PG-1500.	

Notes 1. Low-end model, operating on an external power supply

- 2. The EMU-17K is a product of Naito Densei Machida Seisakusho Co., Ltd.. Contact Naito Densei Machida Seisakusho Co., Ltd. (Kawasaki, 044-822-3813) for details.
- **3.** The EP-17K80GC is supplied together with one EV-9200GC-80. A set of five EV-9200GC-80s is also available.

Remark Third-party PROM programmers are also available: For example, AF-9703, AF-9704, AF-9705, and AF-9706 (manufactured by Ando Electric Co., Ltd.). These PROM programmers can be used with the PA-17P709GC programmer adapter. For details, contact Ando Electric Co., Ltd. (Tokyo, 03-3733-1151).



Software

Name	Description	Host machine	OS	6	Distribution media	Part number
17K series assembler (AS17K)	AS17K is an assembler applicable to the 17K series. In developing μPD17P719 programs, AS17K is used in combination with a device file (AS17707).	PC-9800 MS-DOSTM series			5.25-inch, 2HD	μS5A10AS17K
					3.5-inch, 2HD	μS5A13AS17K
		IBM PC/AT	PC DOSTM		5.25-inch, 2HC	μS7B10AS17K
					3.5-inch, 2HC	μS7B13AS17K
Device file (AS17707)	AS17707 has a device file for the μ PD17P719 . It is used together with the assembler (AS17K), which is applicable to the 17K series.	PC-9800 MS-DOS series		5.25-inch, 2HD	μS5A10AS17707	
					3.5-inch, 2HD	μS5A13AS17707
		IBM PC/AT	PC DOS		5.25-inch, 2HC	μS7B10AS17707
					3.5-inch, 2HC	μS7B13AS17707
Support software (SIMPLEHOST)	SIMPLEHOST, running under Windows TM , provides a man machine interface in developing programs by using a personal computer and incircuit emulator.	PC-9800 series	MS-DOS	Windows	5.25-inch, 2HD	μS5A10IE17K
					3.5-inch, 2HD	μS5A13IE17K
		IBM PC/AT	PC DOS		5.25-inch, 2HC	μS7B10IE17K
					3.5-inch, 2HC	μS7B13IE17K

Remark The following table lists the versions of the operating systems described in the above table.

OS	Versions		
MS-DOS	Ver. 3.30 to Ver.5.00ANote		
PC DOS	Ver. 3.1 to Ver. 5.0 Note		
Windows	Ver. 3.0 to Ver. 3.1		

Note MS-DOS versions 5.00 and 5.00A and PC DOS Ver. 5.0 are provided with a task swap function. This function, however, cannot be used in these software packages.

[MEMO]

[MEMO]

NOTES FOR CMOS DEVICES -

1 PRECAUTION AGAINST ESD FOR SEMICONDUCTORS

Note: Strong electric field, when exposed to a MOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred. Environmental control must be adequate. When it is dry, humidifier should be used. It is recommended to avoid using insulators that easily build static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work bench and floor should be grounded. The operator should be grounded using wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions need to be taken for PW boards with semiconductor devices on it.

(2) HANDLING OF UNUSED INPUT PINS FOR CMOS

Note: No connection for CMOS device inputs can be cause of malfunction. If no connection is provided to the input pins, it is possible that an internal input level may be generated due to noise, etc., hence causing malfunction. CMOS device behave differently than Bipolar or NMOS devices. Input levels of CMOS devices must be fixed high or low by using a pull-up or pull-down circuitry. Each unused pin should be connected to VDD or GND with a resistor, if it is considered to have a possibility of being an output pin. All handling related to the unused pins must be judged device by device and related specifications governing the devices.

(3) STATUS BEFORE INITIALIZATION OF MOS DEVICES

Note: Power-on does not necessarily define initial status of MOS device. Production process of MOS does not define the initial operation status of the device. Immediately after the power source is turned ON, the devices with reset function have not yet been initialized. Hence, power-on does not guarantee out-pin levels, I/O settings or contents of registers. Device is not initialized until the reset signal is received. Reset operation must be executed immediately after power-on for devices having reset function.

[MEMO]

Caution This product contains an I²C bus interface circuit.

When using the I^2C bus interface, notify its use to NEC when ordering custom code. NEC can guarantee the following only when the customer informs NEC of the use of the interface: Purchase of NEC I^2C components conveys a license under the Philips I^2C Patent Rights to use these components in an I^2C system, provided that the system conforms to the I^2C Standard Specification as defined by Philips.

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- · Device availability
- · Ordering information
- · Product release schedule
- · Availability of related technical literature
- Development environment specifications (for example, specifications for third-party tools and components, host computers, power plugs, AC supply voltages, and so forth)
- Network requirements

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